



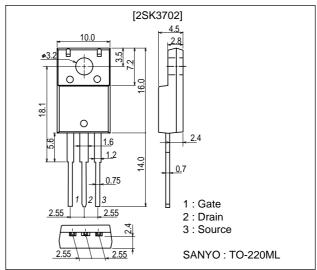
DC / DC Converter Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 4V drive.

Package Dimensions

unit : mm 2063A



Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|--------|------------------------|-------------|------|
| Drain-to-Source Voltage | VDSS | | 60 | V |
| Gate-to-Source Voltage | VGSS | | ±20 | V |
| Drain Current (DC) | ID | | 18 | Α |
| Drain Current (Pulse) | IDP | PW≤10μs, duty cycle≤1% | 72 | Α |
| Allowable Power Dissipation | D- | | 2.0 | W |
| | PD | Tc=25°C | 20 | W |
| Channel Temperature | Tch | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Electrical Characteristics at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|-----------------------------------|----------|--|---------|-----|-----|-------|
| | | | min | typ | max | Offic |
| Drain-to-Source Breakdown Voltage | V(BR)DSS | I _D =1mA, V _{GS} =0 | 60 | | | V |
| Zero-Gate Voltage Drain Current | IDSS | VDS=60V, VGS=0 | | | 1 | μΑ |
| Gate-to-Source Leakage Current | IGSS | V _{GS} = ±16V, V _{DS} =0 | | | ±10 | μΑ |
| Cutoff Voltage | VGS(off) | V _{DS} =10V, I _D =1mA | 1.2 | | 2.6 | V |
| Forward Transfer Admittance | yfs | V _{DS} =10V, I _D =9A | 8 | 12 | | S |

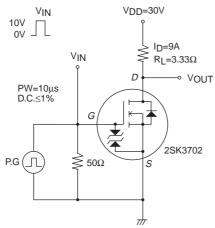
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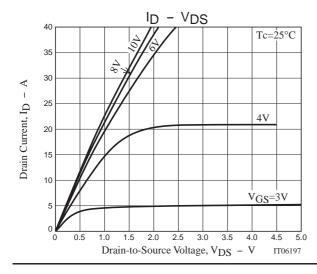
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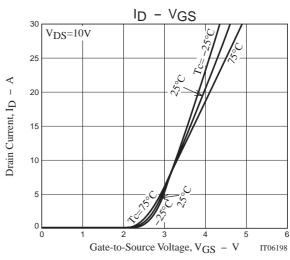
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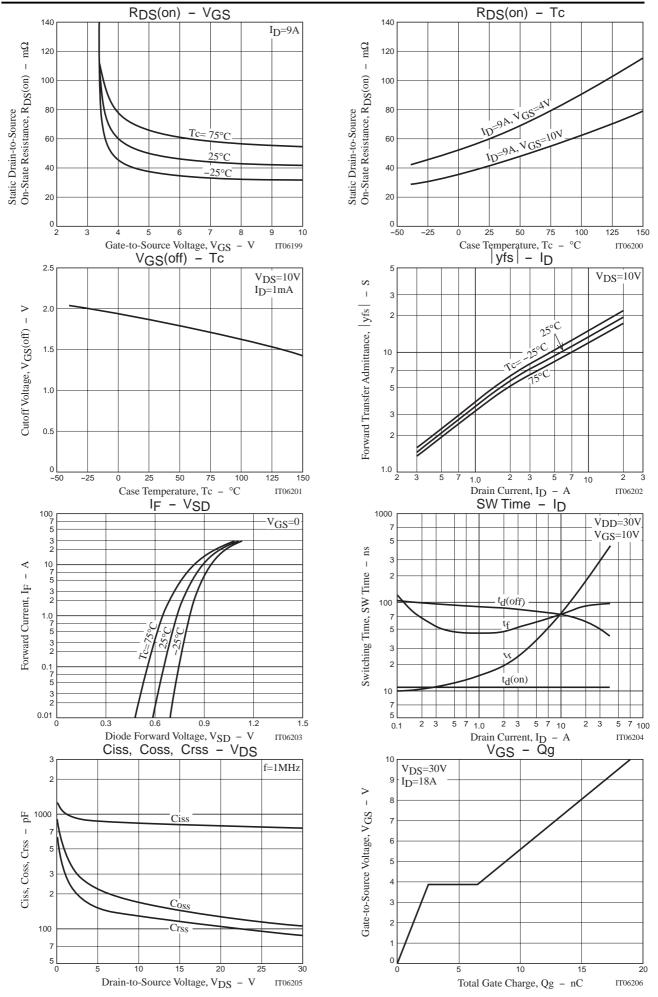
| Parameter | Symbol | Conditions | Ratings | | | Linis |
|--|-----------------------|---|---------|------|-----|-------|
| | | | min | typ | max | Unit |
| Static Drain-to-Source On-State Resistance | R _{DS} (on)1 | I _D =9A, V _{GS} =10V | | 42 | 55 | mΩ |
| | R _{DS} (on)2 | I _D =9A, V _G S=4V | | 60 | 85 | mΩ |
| Input Capacitance | Ciss | V _{DS} =20V, f=1MHz | | 775 | | pF |
| Output Capacitance | Coss | V _{DS} =20V, f=1MHz | | 125 | | pF |
| Reverse Transfer Capacitance | Crss | V _{DS} =20V, f=1MHz | | 105 | | pF |
| Turn-ON Delay Time | td(on) | See specified Test Circuit. | | 11 | | ns |
| Rise Time | t _r | See specified Test Circuit. | | 65 | | ns |
| Turn-OFF Delay Time | t _d (off) | See specified Test Circuit. | | 75 | | ns |
| Fall Time | t _f | See specified Test Circuit. | | 70 | | ns |
| Total Gate Charge | Qg | V _{DS} =30V, V _{GS} =10V, I _D =18A | | 19 | | nC |
| Gate-to-Source Charge | Qgs | V _{DS} =30V, V _{GS} =10V, I _D =18A | | 2.5 | | nC |
| Gate-to-Drain "Miller" Charge | Qgd | V _{DS} =30V, V _{GS} =10V, I _D =18A | | 4.1 | | nC |
| Diode Forward Voltage | V _{SD} | I _S =18A, V _{GS} =0 | | 0.98 | 1.2 | V |

Switching Time Test Circuit

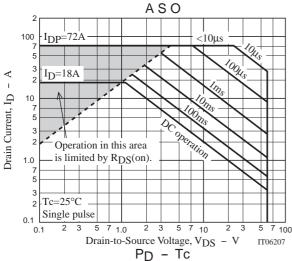


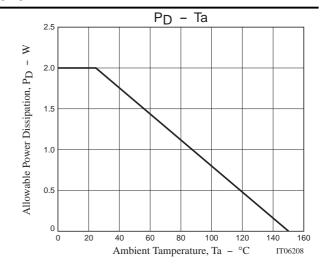


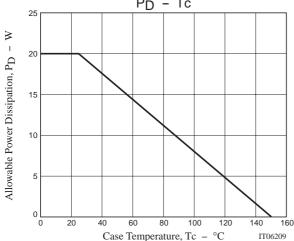




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